

INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor

IRF630N, IIRF630N

FEATURES

- Static drain-source on-resistance: R_Ds(on) ≤0.3Ω
- Enhancement mode
- Fast Switching Speed
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRIPTION

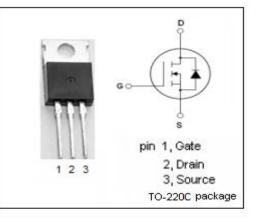
· Efficient and reliable device for use in a wide variety of applications

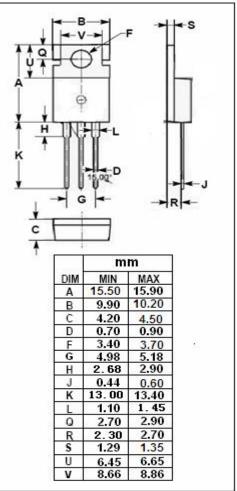
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT			
V _{DSS}	Drain-Source Voltage	200	V			
V _{GS}	Gate-Source Voltage		V			
ID	Drain Current-Continuous	rain Current-Continuous 9.3				
I _{DM}	Drain Current-Single Pulsed	37	А			
PD	Total Dissipation @Tc=25°C	82	W			
Tj	Max. Operating Junction Temperature 175		°C			
T _{stg}	Storage Temperature	-55~175 °C				

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	1.83	°C /W
Rth(ch-a)	Channel-to-ambient thermal resistance	62	°C/W







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ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; ID =250 μ A	200			V
V _{GS} (th)	Gate Threshold Voltage	V _{DS} =V _{GS} ; ID =250 μ A	2		4	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; I _D =5.4A			0.3	Ω
I _{GSS}	Gate-Source Leakage Current	V _{GS} =±20V			±0.1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} =200V; V _{GS} = 0V			25	μA
V _{SD}	Diode forward voltage	I _F =5.4A; V _{GS} = 0V			1.3	V

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